	Preview of Ap	plication for Ph.D. in Electr	onics	
Name	AJAY KUMAR VISVKARMA	Category	Unreserved	Uploaded Files
Gender	Male	Nationality	Indian	
Date of Birth	20-06-1991	Age (As on 01-05-2017)	24 Years 10 Month 12 Days	
Email	ajayvisvkarma13@gmail.com	Mother/Father/Guardian's Name	RAM KIRPAL VISVKARMA	
Mobile	9716222408	University Last Attended	University of Delhi	(http://admission.du
Identity Proof	PAN Card	ID Proof No.	AQBPV1389E	Passport
PwD Category	Not Applicable	Cw Category	Not Applicable	
Writer Assistance Required	Not Applicable	Postal Address	C-92, MOHAN GARDEN, UTTAM NAGAR West Delhi, Delhi - 110059, India	

Department	Electronics	Programme	Ph.D.
Centre Choice	Delhi		

Examination	Stream /	Board /	Year of	Maximum	Marks	Percentage
Passed	Subject	University	Passing	Marks	Obtained	
10+2 or Equivalent	Science	CBSE	2009	500	394	78.80

				200		
B.Sc (Hons)	ELECTRONICS	University of Delhi	2012	1500	1020	68,00
M.Sc	ELECTRONICS	University of Delhi	2014	1400	1012	72.29

Last College: DEPARTMENT OF ELECTRONIC SCIENCE, UDSC

Last University: University of

Delhi

Exam Roll Number (For DU

Students only): 1202

National Level Examination	Other (DRDO-SSPL)				
Title of Fellowship/Scholarship	Certificate No.	Date	Fellowship Amount		
JRF UNDER PROJECT	1149	2016-11-28	32500		
Other Details	Not Applicable				

# Proposed theme and scope of research for M.Phil./Ph.D.

Gallium Nitride based HEMT devices.

Major writings in the field in which you would like to pursue your M.Phil./Ph.D.

Improvement in gate characteristics by reducing gate leakage and improving breakdown.

Primary sources/field work, methodology, hypothesis/research, questions and issues in the proposed field of interest.

# Past Research Experience, Publications

## Additional Information

### For Refund of Fee

Name of
Account
Holder

AJAY KUMAR VISVKARMA

Account Number 235501000090

Name of Bank

ICICI

IFSC Code

ICIC0002355

	Preview of Applic	ation for Ph.D. in Electroni	ics	
Name	Priyanka Pandey	Category	Unreserved	Uploaded Files
Gender	Female	Nationality	Indian	
Date of Birth	04-09-1992	Age (As on 01-05-2017)	24 Years 7 Month 28 Days	
Email	priyanka.pandey004@gmail.com	Mother/Father/Guardian's Name	O.N. Pandey	
Mobile	8447365517	University Last Attended	University of Delhi	(http://admissi
Identity Proof	Driving License	ID Proof No.	DL- 0820100090544	Passport
PwD Category	Not Applicable	Cw Category	Not Applicable	
Writer Assistance Required	Not Applicable	Postal Address	CD-193 F.F. pitampura, Delhi North West Delhi, Delhi - 110034, India	

Department	Electronics	Programme	Ph.D.
Centre Choice	Delhi		

Examination Passed	Stream / Subject	Board / University	Year of Passing	Maximum Marks	Marks Obtained	Percentage
10+2 or Equivalent	Science	CBSE	2010	500	433	86.60
B.Sc (Hons)	Electronics	University of	2013	3600	3137	87.14

7/25/20	17

		Delhi	ission2017/web/index.php/fo		distance			
M.Sc	Electronics	Electronics University o Delhi		1400	1222	87.29		
Electronic Sci	Department of ence, South versity of Delhi	<b>Last Univ</b> Delhi	versity: University o		m Roll Number ( dents only): 1316			
National Leve	el Examination		Not Applicable					
Title of Fellowship/Scholarship			Certificate No.	Date	Date Fellowship Amount			
Other Details			Not Applicable					
Proposed the	eme and scope of r	esearch for M	I.Phil./Ph.D.					
Device model	ing and simulatior	ı, microelectro	nics					
Major writing	gs in the field in w	hich you wou	ld like to pursue yo	our M.Phil./P	h.D.			
would like to	pursue my resea	rch in Device M	odeling and Simula	ation.				
Primary sour		ethodology, h	ypothesis/research	n, questions	and issues in the	proposed		
	n Experience, Pub	l' 4						

# For Refund of Fee

Name of	Priyanka	Account	8668101012541	Name	Canara	IFSC	CNRB0008668
Account	Pandey	Number		of Bank	bank	Code	
Holder							

### Declaration

	Preview	of Application for P	h.D. in Electror	nics	
Name	Monika Sharma	Category		Unreserved	Uploaded Files
Gender	Female	Nationality		Indian	<b>A</b>
Date of Birth	14-04-1992	Age (As on	01-05-2017)	24 Years 0 Month 18 Days	
Email	ankit.sharma43102@gm	nail.com Mother/Fat Name	her/Guardian's	Pradeep Kumar Sharma	
Mobile	9716939367	University	Last Attended	University of Delhi	(http://admission
Identity Proof	Voter's Identity Card	ID Proof No	) <b>.</b>	TPE2029337	Passport
PwD Category	Not Applicable	Cw Categor	у	Not Applicable	
Writer Assistance Required	Not Applicable	Postal Addr	ess	1/7171 SHIVAJI PARK STREET NO. 3, SHAHDARA North East Delhi, Delhi - 110032, India	
Departmen	t El	ectronics	Programme		Ph.D.

Department	Electronics	Programme	Ph.D.
Centre Choice	Delhi		

Examination	Stream /	Board /	Year of	Maximum	Marks	Percentage
Passed	Subject	University	Passing	Marks	Obtained	

10.2.1.93/phdadmission2017/web/index.php/form/final-view?id=2008944

10+2 or Equivalent	Science	CBSE	2010	500	419	83.80
B.Sc (Hons)	ELECTRONICS	University of Delhi	2013	3600	2994	83.17
M.Sc	ELECTRONICS	University of Delhi	2015	1400	1158	82.71

Last College: University of Delhi

Last University: University of

Delhi

Exam Roll Number (For DU

Students only): 1309

National Level Examination	UGC			
Title of Fellowship/Scholarship	Certificate No.	Date	Fellowship Amount	
UGC-NET(LS)	152022308	2016-07-05	0	
Other Details	Not Applicable			

# Proposed theme and scope of research for M.Phil./Ph.D.

I would like to work on the devices such as MOSFET, Tunnel FETs for overcoming the short channel effects and to further use them for low power device applications, digital and analog applications. By using different gate engineering methods we can enhance its characteristics.

# Major writings in the field in which you would like to pursue your M.Phil./Ph.D.

I have done the analytical modeling for Junctionless nanowire Transistor with arbitrary polygonal cross-section in which I have solved the Poisson's equation for the device and verified its results for electric potential and sub-threshold drain current with the ATLAS simulation software for square and circular cross-section. Among circular and square cross-section JNT, square cross-section junctionless nanowire shows better results as it is having lower sub-threshold current and it is also having higher noise margin that means it can be used for digital applications whereas in the case circular cross-section i.e. cylindrical device it require low threshold voltage that means it can used at low power applications and also as fast switches.

Semiconductor have crystal flaws, which caused by dangling bonds present at the interface. The presence of these defects centers, and traps, may significantly influence the characteristics of the device. Trap centers, whose associated energy lies in a forbidden gap, exchange charge with the conduction and valence bands through the emission and capture of electrons. The trap centers influence the density of space charge in

	Preview of App	plication for Ph.D. in Electr	onics	
Name	prashant chaudhary	Category	SC	Uploaded Files
Gender	Male	Nationality	Indian	8
Date of Birth	23-09-1995	Age (As on 01-05-2017)	20 Years 7 Month 9 Days	
Email	prashantelec129@gmail.com	Mother/Father/Guardian's Name	Sheetal Prasad	
Mobile	7503787607	University Last Attended	University of Delhi	(http://admission.du
Identity Proof	Voter's Identity Card	ID Proof No.	NLN2028149	Passport
PwD Category	Not Applicable	Cw Category	Not Applicable	
Writer Assistance Required	Not Applicable	Postal Address	104, Sector - 9, R.K.Puram South West Delhi, Delhi - 110022, India	(http://admission.du

Department	Electronics	Programme	Ph.D.
Centre Choice	Delhi		

Examination Passed	Stream / Subject	Board / University	Year of Passing	Maximum Marks	Marks Obtained	Percentage
10+2 or Equivalent	Science	CBSE	2012	500	347	69.40
B.Sc (Hons)	Electronics	University of	2015	3600	2464	68.44

Name of the last o		Delhi			
M.Sc	Electronics	University of 2017 Delhi	Result Awaited	Result Awaited	Not Applicable

Last College: University of Delhi

Last University: University of

Delhi

Exam Roll Number (For DU Students only): 3620

National Level Examination	Not Applicable		
Title of Fellowship/Scholarship	Certificate No.	Date	Fellowship Amount
Other Details	Not Applicable		

### Proposed theme and scope of research for M.Phil./Ph.D.

microwave antennas

# Major writings in the field in which you would like to pursue your M.Phil./Ph.D.

Well Ideally the application is defined for the signal you are trying to process. It can be anything from audio, video, sensor output, data from the web, in short and simple words any sort of information. So processing it means making the information understandable i.e. like how discrete fourier transforms are used to understand the frequency components of a signal.

signal processing is widely use in filed of data compression, image video edit, and communication and audio processing.

# Primary sources/field work, methodology, hypothesis/research, questions and issues in the proposed field of interest.

Audio signal processing is a highly active research field where digital signal processing theory meets human sound perception and real-time programming requirements. wide range of applications are their such as in computers, gaming, and music technology, etc. form a few to large one. Successful applications include for example perceptual audio coding, digital music synthesizers, and music recognition software. The fact that music is now often listened to using headphones from a mobile device leads to new problems related to background noise control and signal enhancement. Developments in processor technology, such as parallel computing, are changing the way signal-processing algorithms are designed for audio.

some issues that i want to talk about in signal processing

	Preview of	Application for Ph.D. in El	ectronics	
Name	HINA YADAV	Category	Unreserved	Uploaded Files
Gender	Female	Nationality	Indian	A CONTRACTOR OF THE PARTY OF TH
Date of Birth	03-10-1991	Age (As on 01-05-2017)	24 Years 6 Month 29 Days	
Email	hinayadav91@gmail.com	Mother/Father/Guardian's Name	RAKESH YADAV	
Mobile	8802865727	University Last Attended	University of Delhi	(http://admission.du.a
Identity Proof	Aadhar Card	ID Proof No.	708043898132	Passport
PwD Category	Not Applicable	Cw Category	Not Applicable	
Writer Assistance Required	Not Applicable	Postal Address	H no 739 SECTOR 21E, gurgaon Gurgaon, Haryana - 122016, India	

Department	Electronics	Programme	Ph.D.
Centre Choice	Delhi		

Examination Passed	Stream / Subject	Board / University	Year of Passing	Maximum Marks	Marks Obtained	Percentage
10+2 or Equivalent	Science	CBSE	2009	500	333	66.60
B.tech	Electronics and	GBTU	2013	5000	3692	73.84

7/2	51	20	11	7

Last College: UNIVERSITY OF Last University: University of Exam Roll Numb	
M.Tech Microwave University 2015 1800 1312  Electronics of Delhi	2 72.89

Certificate No.

Not Applicable

**Fellowship Amount** 

**Date** 

### Proposed theme and scope of research for M.Phil./Ph.D.

Title of Fellowship/Scholarship

Other Details

RF MEMS reconfigurable multiple wide band Antenna for Spectrum Monitoring as Substrate resistivity

### Major writings in the field in which you would like to pursue your M.Phil./Ph.D.

- 5 months internship at SAMEER (Society for Applied Microwave Electronics and Electrical Research), IIT Campus, Mumbai and worked on "Investigation on Wire Antennas" and designed monopole antenna (3 KHz -3 MHz) and hexagonal Loop Antenna (915 MHz).
- Design, Simulation, Fabrication and Measurement of High Pass Filter at 5 GHz using Microstrip Short stubs.
- A major project on design and simulation of multiband Chaucer fractal patch antenna loaded with dumbbell, fabricated on FR4 material having relative permittivity 4.4 and thickness 1.6 mm. The operating frequency is in the ISM band. The antenna resonates at 5.8 GHz.

Primary sources/field work, methodology, hypothesis/research, questions and issues in the proposed field of interest.

#### Past Research Experience, Publications

- Published a research paper titled "Design and Simulation of Multiband Chaucer Fractal Patch
   Antenna Loaded with Dumbbell" in International Journal of Electronics and Communication
   Engineering and Technology (IJECET), Volume 07, Issue 1.
- Two research papers communicated for ELSEVIER journal Titled, "Investigation of Hexagonal Loop Antenna" and "Active Monopole Antenna for Lightning Detection".



#### 16ESCI2009186

#### Application for Ph.D. in Electronics

Amount	Transaction No.	Payment Date
₹ 500.00	201605305235621	2016-05-30 21:38:06.0

Department	Electronics	Programme Ph.	.D. Centre Choice	Delhi
Name	.monika bansal	Category	General	A
Gender	Female	Nationality	Indian	
Date of Birth	27-09-1993	Age (As on 01-05-2016)	22 Years 7 Month 5 Days	Y
Email	monikabansal2709@gmail.com	Mother/Father/Guardian's N	lame kushal bansal	Your Photo
Mobile	8527941855	University Last Attended	University of Delhi	
Writer Assistance Required	Not Applicable	Postal Address	F-145 second floor s near indian public so Gautam Buddha Nag , India	
Identity Proof	PAN Card	ID Proof No.	CEHPB3000G	Passport Not Applicable

#### **Educational Qualification**

Examination Passed	Subject/ Stre	am Board/ University	Year	Maximum Marks	<b>Marks Obtained</b>	Percentage/CGPA
10+2	Science	RBSE	2010	650	609	93.69
B.Sc (Hons)	electronics	University of Delhi	2014	3600	3141	87.25
M.Sc	electronics	University of Delhi	2016	Result Awaited	Result Awaited	Not Applicable

Last College Attended:	Last Examination Roll Number (For DU Students only):		
department of electronic science	3517		

National Level Examination	UGC		
Title of Fellowship/Scholarship	Certificate No.	Date	Fellowship Amount
junior research fellowship	15028688	2016-04-11	25000
Other Details	Not Applicable		

#### Proposed theme and scope of research for M.Phil./Ph.D.

NOT APPLICABLE

Major writings in the field in which you would like to pursue your M.Phil./Ph.D.

NOT APPLICABLE

Primary sources/field work, methodology, hypothesis/research, questions and issues in the proposed field of interest. NOT APPLICABLE

Past Research Experience, Publications

NOT APPLICABLE

Additional Information

NA

#### **Uploaded Files**

1. Photo 2. Signature 3. ID Proof 4. D.O.B. Certificate

#### Declaration

I have checked all the entries made by me in the form. Any wrong information given by me will lead to cancellation of my admission and also penal action against me.



